

Technical Data Data Sheet N2189, Rev. -





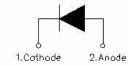
MBRF1660 SCHOTTKY RECTIFIER



Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Maximum Ratings(T_C =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	60	V
Average Rectified Forward Current	I _{F (AV)}	Tc=95°C, In DC	16	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	150	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 16A, Pulse, T _J = 25 °C	0.71	0.75	V
	V_{F2}	@ 16A, Pulse, T _J = 125 °C	0.63	0.65	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.02	1	mA
	I _{R2}	$@V_R = rated V_R$ $T_J = 125 °C$	12	50	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	200	700	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	4.5	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	ITO-220AC			

Ratings and Characteristics Curves

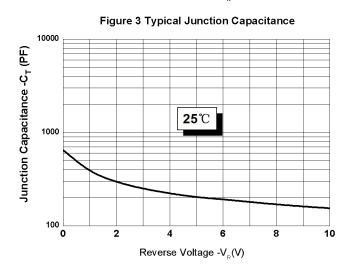
Instantaneous Forward Current -I_p(A)

Forward Voltage -V_F(V)

Figure 1 Typical Forward Characteristics

Figure 2 Typical Reverse Characteristics

To 102 104 105 °C 125 °C 104 104 105 °C 105



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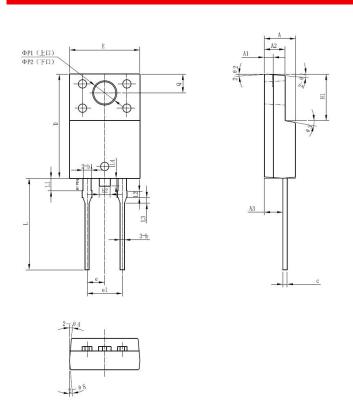


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Mechanical Dimensions ITO-220AC

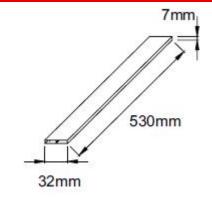


Millimeters					
SYMBOL					
_	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
С	0.55	0.60	0.75		
D	14.80	15.00	15.20		
Ш	9.96	10.16	10.36		
е	_	2.55	-		
e1	-	5.10	-		
H1	6.50	6.70	6.90		
لــ	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
L4	_	1.10	1.50		
ΦP1 (上口)	3.30	3.50	3.70		
ΦP2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

Ordering Information

Device	Package	Shipping	
MBRF1660	ITO-220AC (Pb-Free)	50 pcs/ tube	

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

 MBR
 = Device Type

 F
 = Package type

 16
 = Forward Current (16A)

 60
 = Reverse Voltage (60V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

 Cautions:
 Molding resin

Enovy resin l

Epoxy resin UL:94V-0

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